350nA 7KHZ CMOS Rail-to-Rail IO Opamp with RF Filter

Features

Single-Supply Operation from +1.4V ~ +5.5V

Rail-to-Rail Input / Output

Gain-Bandwidth Product: 7KHz (Typ)

Low Input Bias Current: 1pA (Typ)

Low Offset Voltage: 3mV (Max)

• Quiescent Current: 350nA per Amplifier (Typ)

• Chip Select with GS8143NH(active High) and

GS8143NL(active Low)

Operating Temperature: -40°C ~ +125°C

• Embedded RF Anti-EMI Filter

• Small Package:

GS8141 Available in SOT23-5 and SC70-5 Packages GS8142 Available in SOP-8 and MSOP-8 Packages GS8143NH Available in SOT23-6 and SC70-6 Packages GS8143NL Available in SOT23-6 and SC70-6 Packages

General Description

The GS814X family has a high gain-bandwidth product of 7KHz, a slew rate of 3V/ms, and a quiescent current of 350nA/amplifier at 5V. The GS814X family is designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3mV for GS814X family. They are specified over the extended industrial temperature range (-40 °C to +125 °C). The operating range is from 1.4V to 5.5V. The GS8141 single is available in Green SC70-5 and SOT23-5 packages. The GS8142 Dual is available in Green SOP-8 and MSOP-8 packages. The GS8143 single is available in Green SC70-6 and SOT23-6 packages.

Applications

- ASIC Input or Output Amplifier
- Sensor Interface
- Medical Communication
- Smoke Detectors

- Audio Output
- Piezoelectric Transducer Amplifier
- Medical Instrumentation
- Portable Systems

Pin Configuration

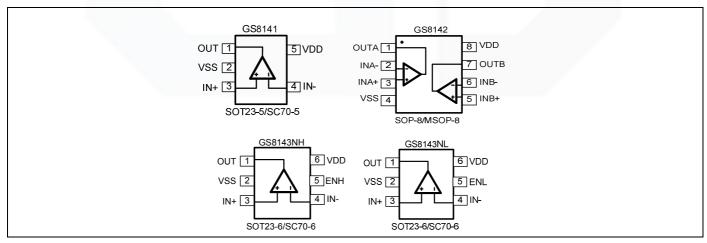


Figure 1. Pin Assignment Diagram





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Absolute Maximum Ratings

Condition	Min	Max
Power Supply Voltage (V _{DD} to Vss)	-0.5V	+7.5V
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V _{DD} +0.5V
PDB Input Voltage	Vss-0.5V	+7V
Operating Temperature Range	-40°C	+125°C
Junction Temperature	+160	°C
Storage Temperature Range	-55°C	+150°C
Lead Temperature (soldering, 10sec)	+260	°C
Package Thermal Resistance (T _A =+25℃)		
SOP-8, θ _{JA}	125°C	C/W
MSOP-8, θ_{JA}	216°C	C/W
SOT23-5, θ _{JA}	190°C	C/W
SOT23-6, θ _{JA}	190°C	C/W
SC70-5, θ _{JA}	333°C	C/W
SC70-6, θ _{JA}	333°C/W	
ESD Susceptibility		
НВМ	6K\	/
MM	300V	

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Package/Ordering Information

MODEL	CHANNEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
GS8141	Cinalo	GS8141-CR	SC70-5	Tape and Reel,3000	8141
G30141	Single	GS8141-TR	SOT23-5	Tape and Reel,3000	8141
CC0440	Dual	GS8142-SR	SOP-8	Tape and Reel,4000	GS8142
GS8142	Duai	GS8142-MR	MSOP-8	Tape and Reel,3000	GS8142
CC04.42NII.I	Cimalo	GS8143NH-CR	SC70-6	Tape and Reel,4000	143H
GS8143NH Single	GS8143NH-TR	SOT23-6	Tape and Reel,3000	GS8143NH	
000440011	GS8143NL-CR	SC70-6	Tape and Reel,4000	143L	
GS8143NL	Single	GS8143NL-TR	SOT23-6	Tape and Reel,3000	GS8143NL







Electrical Characteristics

(At V_S = +5V, R_L = 1M Ω connected to $V_S/2$, and V_{OUT} = $V_S/2$, unless otherwise noted.)

DADAMETED	OVALDO	COMPLETIONS	GS8141/8142/8143			
PARAMETER	SYMBOL	CONDITIONS	TYP	MIN	MAX	UNITS
INPUT CHARACTERISTICS						•
Input Offset Voltage	Vos	$V_{CM} = V_S/2$	0.4		3	mV
Input Bias Current	I _B		1			pA
Input Offset Current	Ios		1			pА
Common-Mode Voltage Range	V _{CM}	V _S = 5.5V	-0.1 to +5.6			V
Communication Model Delication Detic	CMPD	$V_S = 5V$, $V_{CM} = -0.1V$ to 2.5V	77	63		٦D
Common-Mode Rejection Ratio	CMRR	V _S = 5V, V _{CM} = -0.1V to 5.1V	83	68		ав
0 1 1/4 0:		$Vs=1.4V, R_L = 50k\Omega, V_O = Vs-0.1V$	84	75		ID.
Open-Loop Voltage Gain	pen-Loop Voltage Gain A _{OL}	Vs=5V, R_L = 50k Ω , V_O = Vs-0.1V	93	87		ав
Input Offset Voltage Drift	$\Delta V_{OS}/\Delta_T$		2.5			μV/°C
OUTPUT CHARACTERISTICS						
	V_{OH}	V 4.0/ D 50/0	1.395	1.390		V mV V mV
0.1.17/110:	V _{OL}	Vs=1.4V, R_L = 50kΩ	4.5		10	
Output Voltage Swing from Rail	V _{OH}	V 5V D 5010	4.997	4.990		
	V _{OL}	Vs=5V, $R_L = 50k\Omega$	3.5		10	mV
0.1.10	I _{SOURCE}	D 400 L V 40	20			
Output Current	I _{SINK}	$R_L = 10\Omega$ to $V_S/2$	20			mA
POWER SUPPLY						
0 " " " "			1.4			V
Operating Voltage Range			5.5			V mV V mA
Power Supply Rejection Ratio	PSRR	$V_S = +1.4V \text{ to } +5.5V, V_{CM} = +0.5V$	80	69		dB
Quiescent Current / Amplifier	IQ		600			nA
Shutdown Current / Amplifier	I _{Q_off}	GS8143NH / GS8143NL	54			nA
DYNAMIC PERFORMANCE (CL	= 100pF)					
Gain-Bandwidth Product	GBP		7			KHz
Slew Rate	SR	G = +1, 2V Output Step	3			V/ms

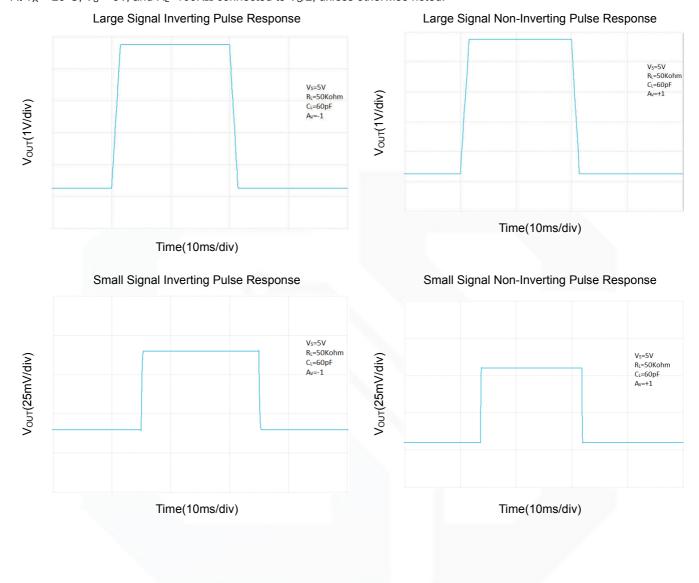






Typical Performance characteristics

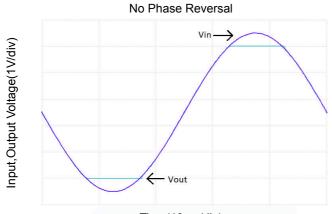
At T_A =+25°C, V_S =+5V, and R_L =100K Ω connected to V_S /2, unless otherwise noted.



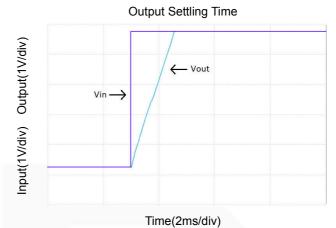


Typical Performance characteristics

At T_A =+25°C, V_S =+5V, and R_L =100K Ω connected to $V_S/2$, unless otherwise noted.







GAINSI<u>L</u>



Application Note

Size

GS814X family series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the GS814X family packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

GS814X family series operates from a single 1.4V to 5.5V supply or dual $\pm 0.7V$ to $\pm 2.75V$ supplies. For best performance, a 0.1 μ F ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate 0.1 μ F ceramic capacitors.

Low Supply Current

The low supply current (typical 350nA per channel) of GS814X family will help to maximize battery life. They are ideal for battery powered systems.

Operating Voltage

GS814X family operates under wide input supply voltage (1.4V to 5.5V) In addition, all temperature specifications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-lon battery lifetime.

Rail-to-Rail Input

The input common-mode range of GS814X family extends 100mV beyond the supply rails (V_{SS} -0.1V to V_{DD} +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of GS814X family can typically swing to less than 50mV from supply rail in light resistive loads ($>50k\Omega$).

Capacitive Load Tolerance

The GS814X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

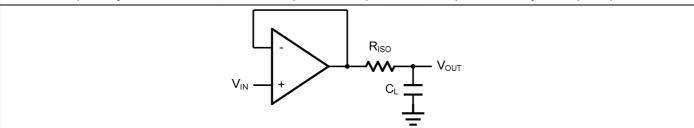


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor







The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO}/R_L) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L . C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F . This in turn will slow down the pulse response.

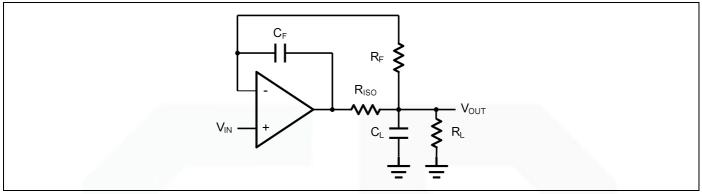


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy







Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using GS814X family.

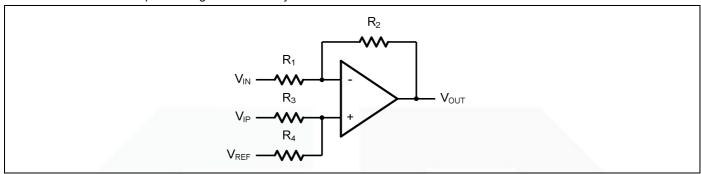


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + (\frac{R_1 + R_2}{R_3 + R_4}) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. R₁=R₃ and R₂=R₄), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_C=1/(2\pi R_3C_1)$.

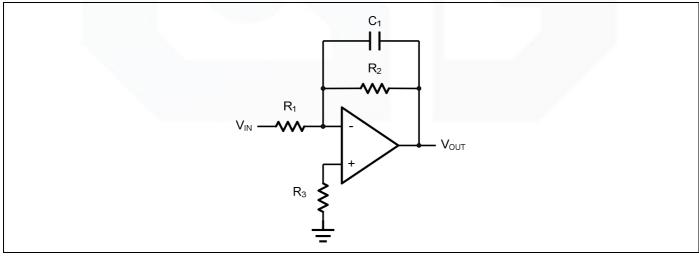


Figure 5. Low Pass Active Filter



Instrumentation Amplifier

The triple GS814X family can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R2/R1. The two differential voltage followers assure the high input impedance of the amplifier.

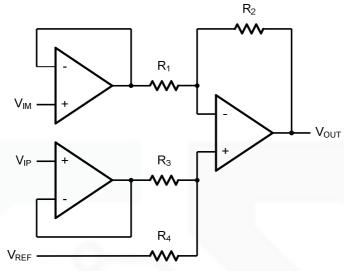


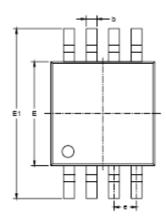
Figure 6. Instrument Amplifier

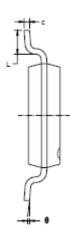


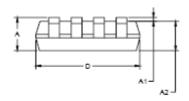


Package Information

MSOP-8



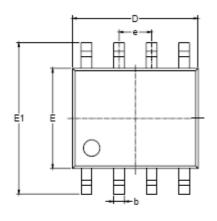


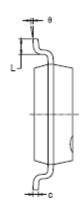


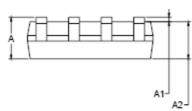
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.008
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
С	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.650 BSC		0.026	BSC
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°



SOP-8



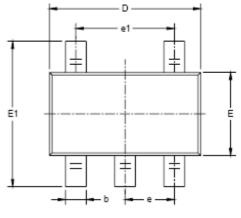


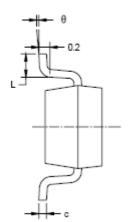


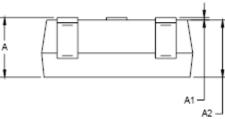
Symbol		Dimensions In Millimeters		isions ches
_	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
С	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27	1.27 BSC		BSC
L	0.400	1.270	0.016	0.050
е	0°	8°	0°	8°



SOT23-5



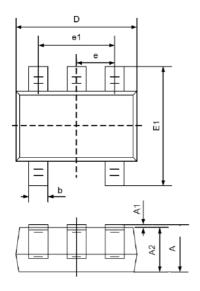


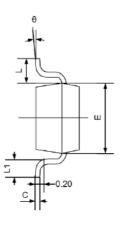


Symbol	Dimensions In Millimeters		Dimensions In Inches	
-	MIN	MAX	MIN	MAX
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950	BSC	0.037 BSC	
e1	1.900	1.900 BSC		BSC
L	0.300	0.600	0.012	0.024
ө	0°	8°	0°	8°



SC70-5

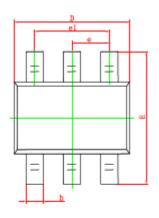


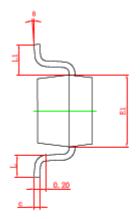


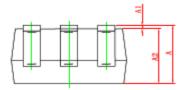
	Dimensions		Dimens	sions
Symbol	In Milli	meters	In Inches	
	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650T	ΥP	0.026TYP	
e1	1.200	1.400	0.047	0.055
L	0.525R	0.525REF		EF
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°



SC70-6



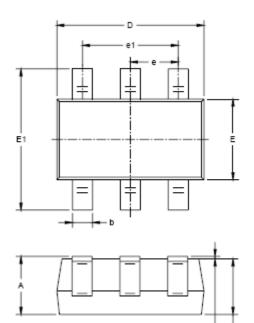


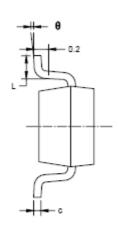


Symbol	Dimensions	In Millimeters	Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	2.150	2.450	0.085	0.096
E1	1.150	1.350	0.045	0.053
e	0.650	TYP.	0.026	TYP.
e1	1.200	1.400	0.047	0.055
L	0.260	0.460	0.010	0.018
L1	0.525 REF.		0.021	REF.
θ	0°	8°	0°	8°



SOT23-6





Symbol	Dimensions In Millimeters		Dimensions In Inches	
-,	MIN	MAX	MIN	MAX
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.087
E1	2.650	2.950	0.104	0.116
e	0.950	BSC	0.037	BSC
e1	1.900 BSC		0.075	BSC
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

A1 -